



RS1MSWFMQ

Product Summary (@T_A = +25°C)

V _{RRM} (V)	I _O (A)	V _F Max (V)	I _R Max (μA)	t _{rr} Max (ns)
1,000	1	1.3	10	500

Description and Applications

The DIODES[™] RS1MSWFMQ is a rectifier packaged in the SOD123F (Type B) package. Providing fast recovery time for high efficiency, this device is ideal for applications such as:

- Reverse protections
- Switching
- Blocking

1.0A SURFACE MOUNT FAST RECOVERY RECTIFIER

Features and Benefits

- Glass Passivated Die Construction
- Fast Recovery Time for High Efficiency
- Small Form Factor, Low Profile
- Ideally Suited for Automated Assembly
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The RS1MSWFMQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOD123F
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)

1 0

- Polarity: Cathode Band
- Weight: 0.018 grams (Approximate)



Top View



Bottom View

CATHODE ANODE

Schematic View

0 2

Ordering Information (Note 4)

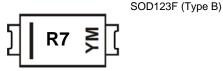
Part Number	Package	Packing		
Fait Nulliper	Гаскауе	Qty.	Carrier	
RS1MSWFMQ-7	SOD123F (Type B)	3,000	Tape & Reel	

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



R7 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: J = 2022)

M = Month (ex: 8 = August)

Date Code Key

Notes:

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	J	К	L	М	Ν	0	Р	R	S	Т	U	V
	-											
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

SOD123F (Type B)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _{RM}	1,000	V
RMS Reverse Voltage		V _{R(RMS)}	700	V
Average Rectified Output Current	@T _A = +75°C	lo	1.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on F	ated Load	I _{FSM}	25	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Case (Note 5)	R _{θJC}	13	°C/W
Thermal Resistance Junction to Ambient (Note 5)	R _{θJA}	82	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	С

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	V _{(BR)R}	1,000	—	—	V	I _R = 5μA
Forward Voltage Drop	VF		1.1 0.98	1.3	V	I _F = 1A, T _J = +25°C I _F = 1A, T _J = +125°C
Leakage Current (Note 6)	I _R		0.3 19	10 200	μA	V _R = 1,000V, T _J = +25°C V _R = 1,000V, T _J = +125°C
Reverse Recovery Time	t _{rr}	—	148	500	ns	$I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A$
Total Capacitance	CT	—	4.7	—	pF	$V_R = 4.0V_{DC}$, f = 1MHz

Notes: 5. Device mounted on FR4 PCB with 1x recommended pad layout, 1inch 2oz, as shown on Diodes Incorporated's website at http://www.diodes.com/package-outlines.html.

6. Short duration pulse test used to minimize self-heating effect.



RS1MSWFMQ

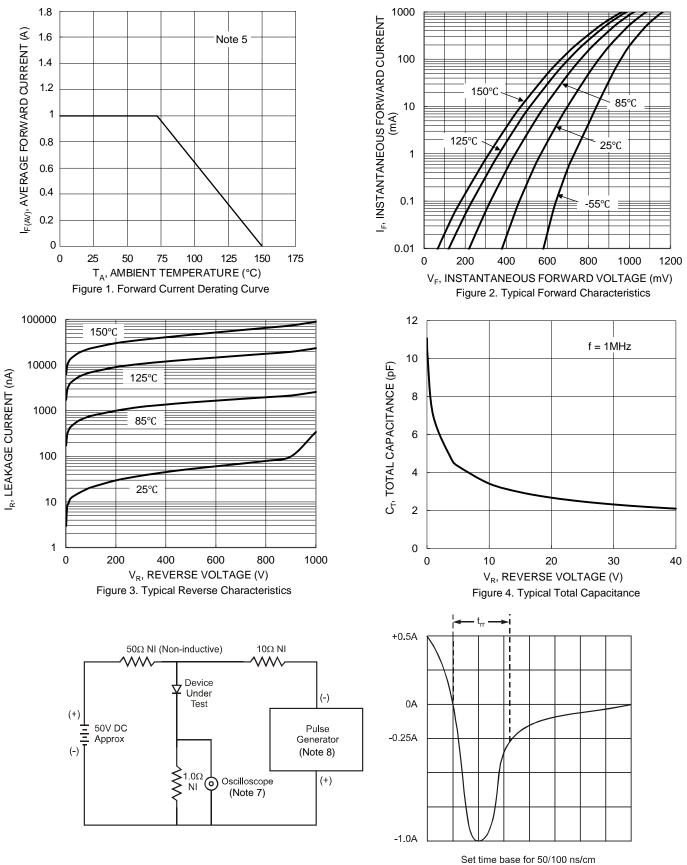


Figure 5. Reverse Recovery Time Characteristic and Test Circuit

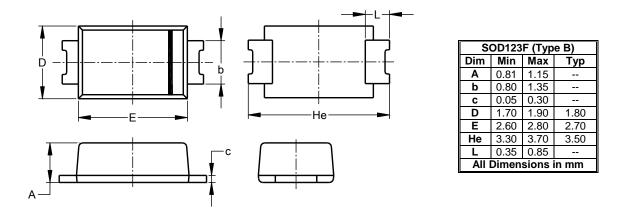
Notes: 7. Rise time = 7.0ns max. Input impedance = $1.0M\Omega$, 22pF. 8. Rise time = 10ns max. Input impedance = 50Ω .



Package Outline Dimensions

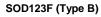
Please see http://www.diodes.com/package-outlines.html for the latest version.

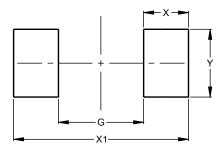
SOD123F (Type B)



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)
G	1.90
Х	1.00
X1	3.90
Y	1.50



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